

# SILICON POWER TRANSISTOR 2SA1743

# PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SA1743 is a power transistor developed for high-speed switching and features a high hee at low Vce(sat). This transistor is ideal for use as a driver in DC/DC converters and actuators.

In addition, a small resin-molded insulation type package contributes to high-density mounting and reduction of mounting cost.

#### **FEATURES**

- High hee and low VcE(sat): hfe  $\geq$  100 (Vce = -2 V, Ic = -2 A)  $V CE(sat) \le 0.3 V (IC = -6 A, IB = -0.3 A)$
- · Full-mold package that does not require an insulating board or bushing

#### **QUALITY GRADES**

Standard

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document No. C11531E) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

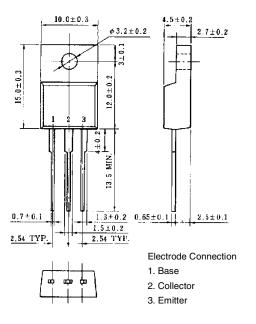
Parameter	Symbol	Ratings	Unit
Collector to base voltage	Vcво	-100	V
Collector to emitter voltage	VCEO	-60	V
Emitter to base voltage	VEBO	-7.0	V
Collector current (DC)	Ic(DC)	-10	Α
Collector current (pulse)	IC(pulse)*	-20	Α
Base current (DC)	I <sub>B(DC)</sub>	-5.0	Α
Total power dissipation	P <sub>T</sub> (Tc = 25°C)	30	W
Total power dissipation	P⊤ (Ta = 25°C)	2.0	W
Junction temperature	Tj	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

<sup>\*</sup> PW  $\leq$  300  $\mu$ s, duty cycle  $\leq$  10%

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Not all devices/types available in every country. Please check with local NEC representative for

### PACKAGE DRAWING (UNIT: mm)





# ELECTINGAL4CHARACTERISTICS (Ta = 25°C)

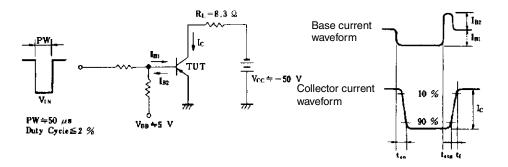
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector to emitter voltage	VCEO(SUS)	Ic = -6.0 A, I <sub>B</sub> = -0.6 A, L = 1 mH -60				V
Collector to emitter voltage	VCEX(SUS)	Ic = $-6.0$ A, I <sub>B1</sub> = $-I$ <sub>B2</sub> = $-0.6$ A, V <sub>BE(OFF)</sub> = $1.5$ V, L = $180~\mu$ H, clamped	-60			V
Collector cutoff current	Ісво	Vcb = -60 V, IE = 0			-10	μΑ
Collector cutoff current	ICER	$V_{CE} = -60 \text{ V}, \text{ RBE} = 50 \Omega, \text{ Ta} = 125^{\circ}\text{C}$			-1.0	mA
Collector cutoff current	ICEX1	$V_{CE} = -60 \text{ V}, V_{BE(OFF)} = 1.5 \text{ V}$			-10	μΑ
Collector cutoff current	ICEX2	Vce = -60 V, Vbe(OFF) = 1.5 V, Ta = 125°C			-1.0	mA
Emitter cutoff current	ІЕВО	V <sub>EB</sub> = -5.0 V, I <sub>C</sub> = 0			-10	μΑ
DC current gain	hFE1*	Vce = -2.0 V, Ic = -1.0 A	100			
DC current gain	hFE2*	Vce = -2.0 V, Ic = -2.0 A	100		400	
DC current gain	h <sub>FE3</sub> *	Vce = -2.0 V, Ic = -6.0 A	60			
Collector saturation voltage	VCE(sat)1*	Ic = -6.0  A, IB = -0.3  A			-0.3	V
Collector saturation voltage	VCE(sat)2*	Ic = -8.0  A, IB = -0.4  A			-0.5	V
Base saturation voltage	V <sub>BE(sat)1</sub> *	Ic = -6.0  A, IB = -0.3  A			-1.2	V
Base saturation voltage	V <sub>BE(sat)2</sub> *	Ic = -8.0  A, IB = -0.4  A			-1.5	V
Collector capacitance	Сор	VcB = −10 V, IE = 0, f = 1.0 MHz		230		pF
Gain bandwidth product	f⊤	Vce = -10 V, Ic = -1.0 A		80		MHz
Turn-on time	ton	Ic = $-6.0$ A, RL = $8.3$ $\Omega$ ,			0.3	μs
Storage time	tstg	$I_{B1} = -I_{B2} = -0.3 \text{ A}, \text{ Vcc} \cong -50 \text{ V}$ Refer to the test circuit.			1.5	μs
Fall time	tf	nerer to the test circuit.			0.3	μs

<sup>\*</sup> Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2%

### **hfe CLASSIFICATION**

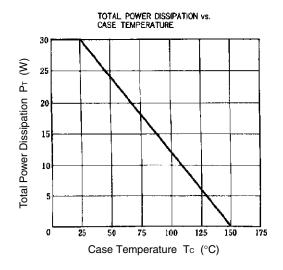
Marking	M	L	K
h <sub>FE2</sub>	100 to 200	150 to 300	200 to 400

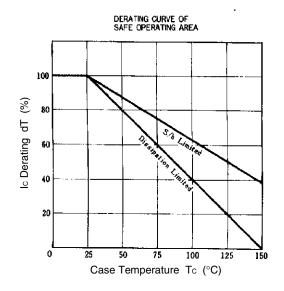
## SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

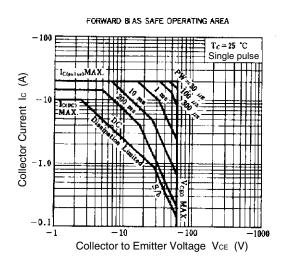


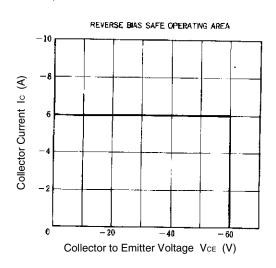


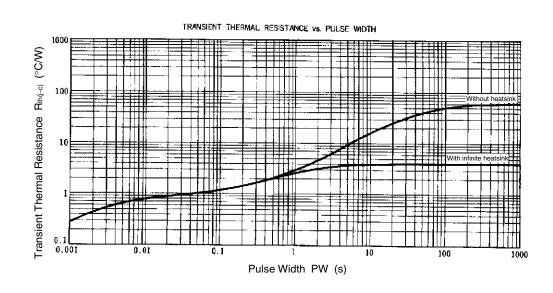
# 查询"28P4CA(3"(共AFA)CTERISTICS (Ta = 25°C)









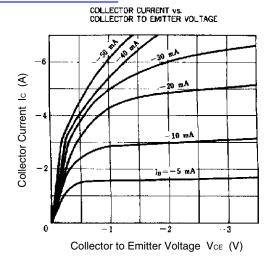


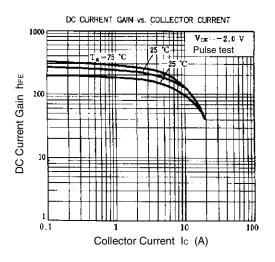
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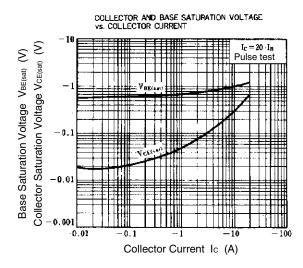
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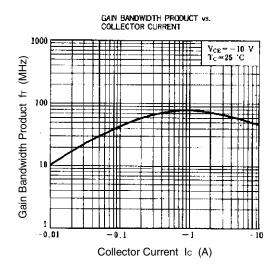


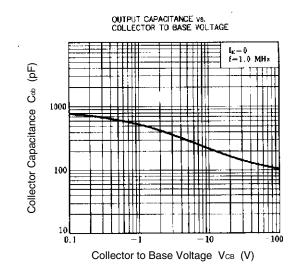
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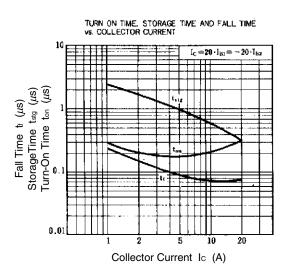














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